

Title (en)  
NEURAL NETWORK CIRCUITS HAVING NON-VOLATILE SYNAPSE ARRAYS

Title (de)  
SCHALTUNGEN NEURONALER NETZE MIT NICHTFLÜCHTIGEN SYNAPSENARRAYS

Title (fr)  
CIRCUITS DE RÉSEAU NEURONAL COMPRENANT DES SÉRIES DE SYNAPSES NON VOLATILES

Publication  
**EP 3743857 A4 20211229 (EN)**

Application  
**EP 19744289 A 20190122**

Priority

- US 201862620947 P 20180123
- US 201862655074 P 20180409
- US 201816196617 A 20181120
- US 201916252640 A 20190120
- US 2019014442 W 20190122

Abstract (en)  
[origin: WO2019147522A2] A synapse circuit of a non-volatile neural network. The synapse includes: an input signal line (265); a reference signal line (265); an output line (266), and a cell (2032) for generating the output signal (203). The cell (2032) includes: an upper select transistor (311) having a gate that is electrically coupled to the input signal line (265); and a resistive changing element (313) having one end connected to the upper select transistor (311) in series and another end electrically coupled to the reference signal line (264). The value of the resistive changing element (311) is programmable to change the magnitude of an output signal (203). The drain of the upper select transistor (311) is electrically coupled to the output line (266).

IPC 8 full level  
**G06N 3/04** (2006.01); **G06N 3/063** (2006.01); **G06N 3/08** (2006.01); **G11C 11/54** (2006.01); **G11C 11/56** (2006.01); **G11C 13/00** (2006.01)

CPC (source: EP KR)  
**G06N 3/048** (2023.01 - EP KR); **G06N 3/063** (2013.01 - KR); **G06N 3/065** (2023.01 - EP); **G06N 3/08** (2013.01 - EP KR); **G11C 11/54** (2013.01 - EP KR); **G11C 11/5614** (2013.01 - KR); **G11C 11/5685** (2013.01 - KR); **G11C 13/0028** (2013.01 - EP KR); **G11C 13/003** (2013.01 - EP KR); **G11C 13/004** (2013.01 - EP KR); **G11C 13/0069** (2013.01 - EP KR); **G11C 13/0097** (2013.01 - EP KR); **G11C 11/5614** (2013.01 - EP); **G11C 11/5685** (2013.01 - EP); **G11C 2013/0092** (2013.01 - EP KR); **G11C 2213/79** (2013.01 - EP KR); **G11C 2213/82** (2013.01 - EP KR)

Citation (search report)

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Designated contracting state (EPC)  
AL AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HR HU IE IS IT LI LT LU LV MC MK MT NL NO PL PT RO RS SE SI SK SM TR

DOCDB simple family (publication)  
**WO 2019147522 A2 20190801**; **WO 2019147522 A3 20200409**; CN 111656371 A 20200911; CN 111656371 B 20240604; EP 3743857 A2 20201202; EP 3743857 A4 20211229; KR 102567160 B1 20230816; KR 20200110701 A 20200924; TW 201937413 A 20190916; TW I751403 B 20220101

DOCDB simple family (application)  
**US 2019014442 W 20190122**; CN 201980009706 A 20190122; EP 19744289 A 20190122; KR 20207024195 A 20190122; TW 108102597 A 20190123